

N-Channel Enhancement-Mode MOSFET Transistors

PRODUCT SUMMARY

Part Number	$V_{(BR)DSS}$ Min (V)	$r_{DS(on)}$ Max (Ω)	$V_{GS(th)}$ (V)	I_D (A)
TN2410L	240	10 @ $V_{GS} = 4.5$ V	0.5 to 1.8	0.18
VN2406D		6 @ $V_{GS} = 10$ V	0.8 to 2	1.12
VN2406L		6 @ $V_{GS} = 10$ V	0.8 to 2	0.18
VN2410L		10 @ $V_{GS} = 10$ V	0.8 to 2	0.18
VN2410LS		10 @ $V_{GS} = 10$ V	0.8 to 2	0.19

FEATURES

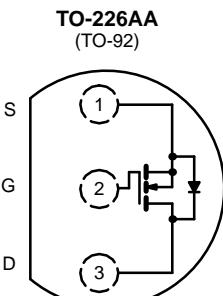
- Low On-Resistance: 3.5Ω
- Secondary Breakdown Free: 260 V
- Low Power/Voltage Driven
- Low Input and Output Leakage
- Excellent Thermal Stability

BENEFITS

- Low Offset Voltage
- Full-Voltage Operation
- Easily Driven Without Buffer
- Low Error Voltage
- No High-Temperature "Run-Away"

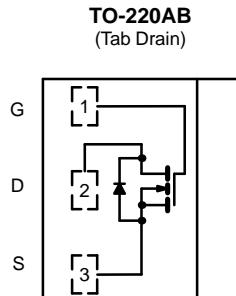
APPLICATIONS

- High-Voltage Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Transistors, etc.
- Telephone Mute Switches, Ringer Circuits
- Power Supply, Converters
- Motor Control



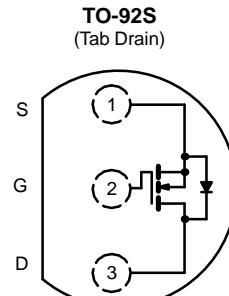
Top View

TN2410L
VN2406L
VN2410L



Top View

VN2406D



Top View

VN2410LS

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	TN2410L	VN2406D ^b	VN2406L	VN2410L	VN2410LS	Unit
Drain-Source Voltage	V_{DS}	240	240	240	240	240	V
Gate-Source Voltage	V_{GS}	± 20	± 20	± 20	± 20	± 20	
Continuous Drain Current ($T_J = 150^\circ\text{C}$)	I_D	0.18	1.12	0.18	0.18	0.19	A
		0.11	0.7	0.11	0.11	0.12	
Pulsed Drain Current ^a	I_{DM}	1	3	1.7	1.7	2	
Power Dissipation	P_D	0.8	20	0.8	0.8	0.9	W
		0.32	8	0.32	0.32	0.4	
Maximum Junction-to-Ambient	R_{thJA}	156	6.25 ^c	156	156	139	°C/W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	−55 to 150					°C

Notes

- Pulse width limited by maximum junction temperature.
- Reference case for all temperature testing.
- Maximum junction-to-case

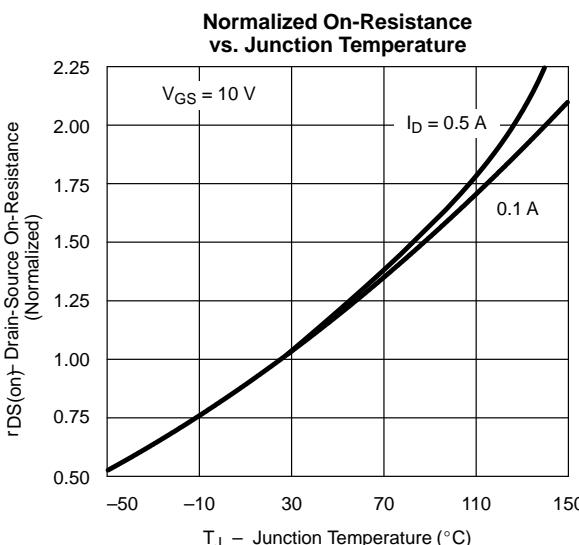
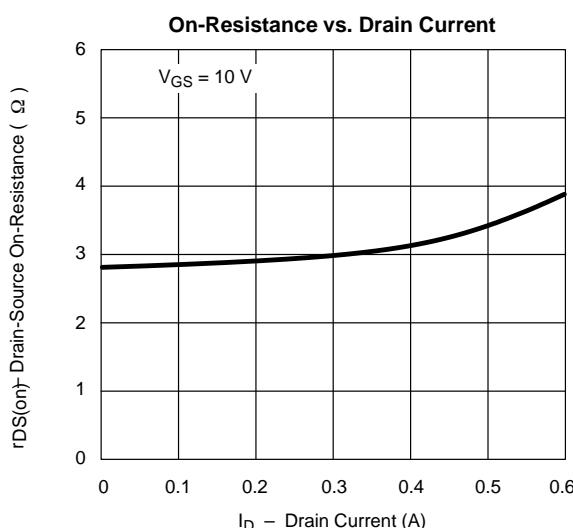
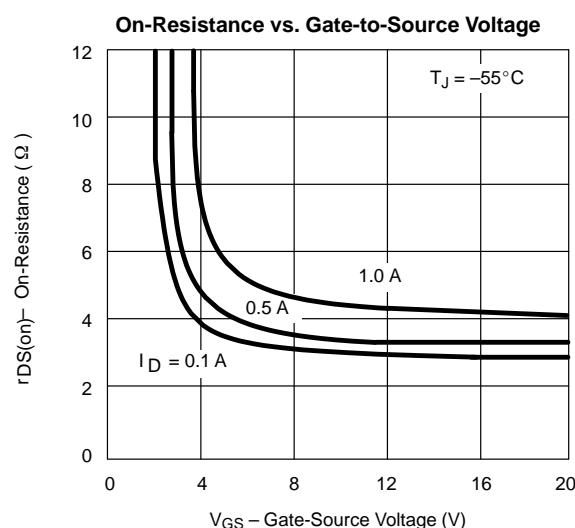
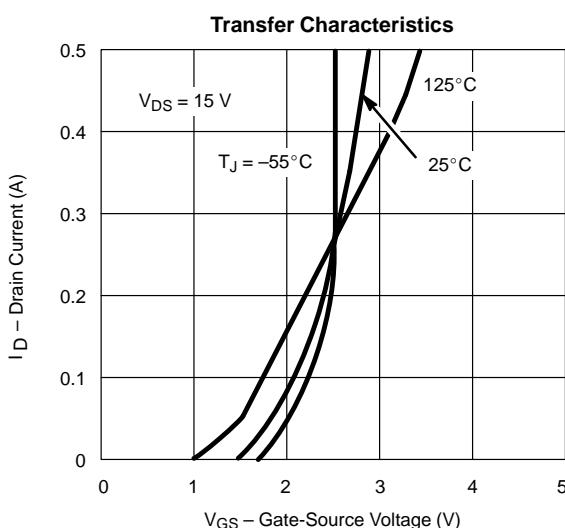
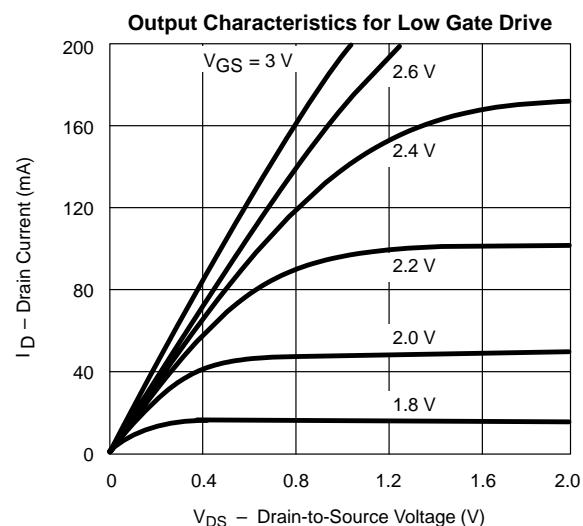
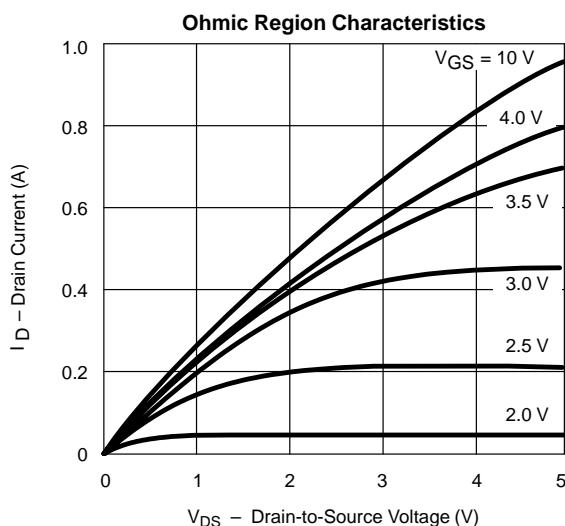
SPECIFICATIONS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED)

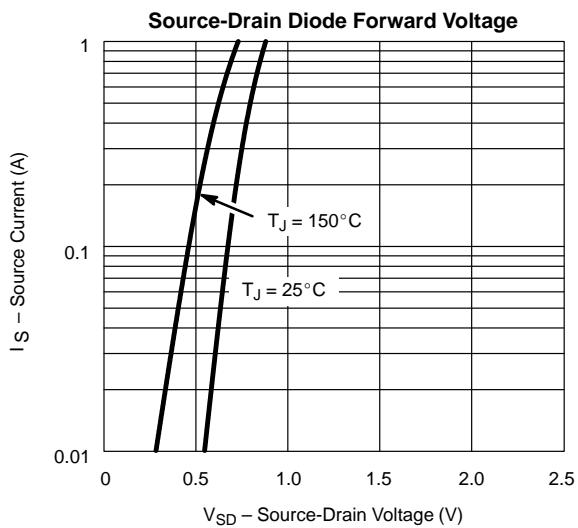
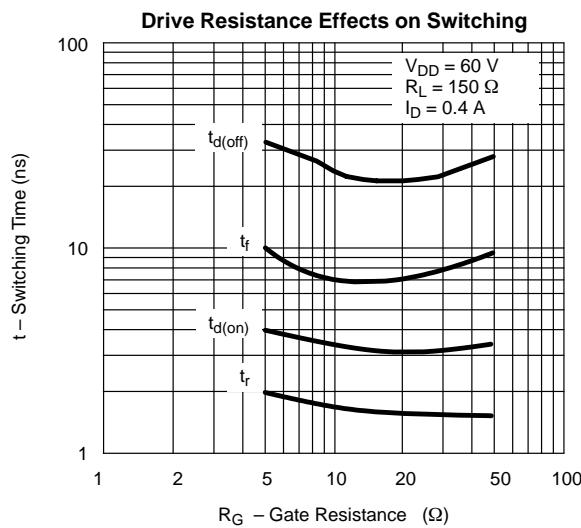
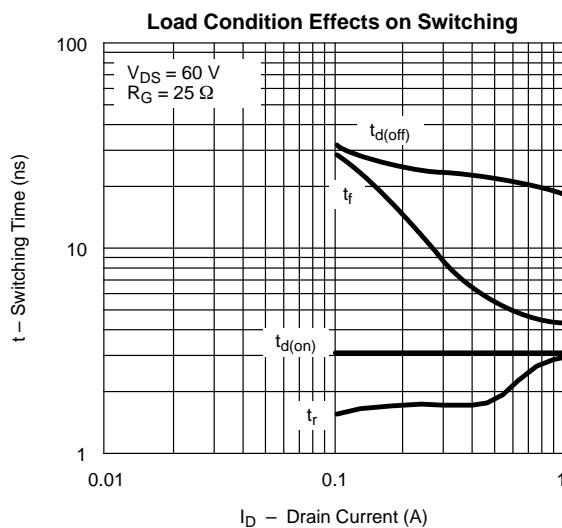
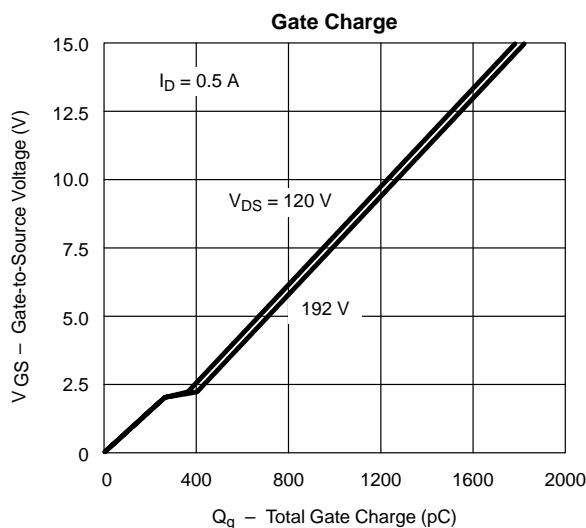
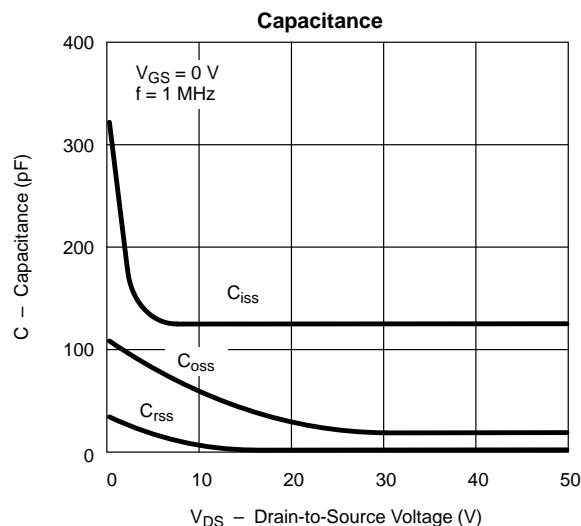
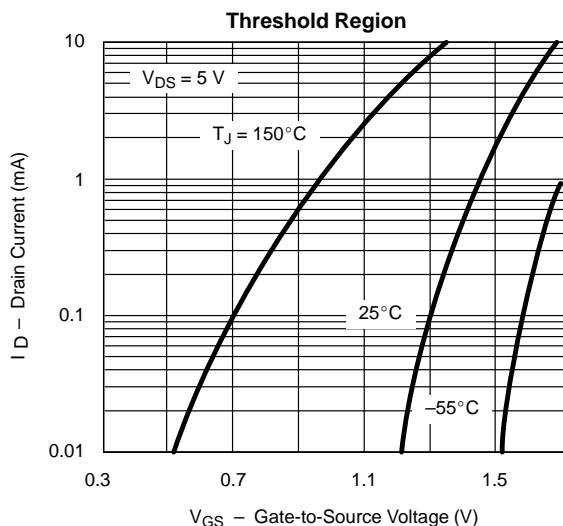
Parameter	Symbol	Test Conditions	Typ ^a	Limits						Unit	
				TN2410L		VN2406D/L		VN2410L/LS			
				Min	Max	Min	Max	Min	Max		
Static											
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0 \text{ V}, I_D = 100 \mu\text{A}$	260	240		240		240		V	
Gate-Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 1 \text{ mA}$	1.4	0.5	1.8	0.8	2	0.8	2		
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 15 \text{ V}$					± 100		± 100	nA	
		$T_J = 125^\circ\text{C}$					± 500		± 500		
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 10					μA	
		$V_{DS} = 192 \text{ V}, V_{GS} = 0 \text{ V}$	0.01		1						
		$T_J = 125^\circ\text{C}$	1		100						
		$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}$					10		10		
On-State Drain Current ^b	$I_{D(on)}$	$T_J = 125^\circ\text{C}$					500		500	A	
		$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}$	0.8	0.25							
Drain-Source On-Resistance ^b	$r_{DS(on)}$	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}$	1.5			1		1		Ω	
		$V_{GS} = 2.5 \text{ V}, I_D = 0.1 \text{ A}$	7.5				10		10		
		$V_{GS} = 3.5 \text{ V}, I_D = 0.05 \text{ A}$	4.5		15						
		$V_{GS} = 4.5 \text{ V}, I_D = 0.2 \text{ A}$	4		10						
		$T_J = 125^\circ\text{C}$	7.5		20						
		$V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$	3.5				6		10		
Forward Transconductance ^b	g_{fs}	$T_J = 125^\circ\text{C}$	6.5				14.8		24.7	mS	
		$V_{DS} = 10 \text{ V}, I_D = 0.2 \text{ A}$	500	100							
Input Capacitance	C_{iss}	$V_{DS} = 10 \text{ V}, I_D = 0.5 \text{ A}$	530			300		300		pF	
	C_{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}$ $f = 1 \text{ MHz}$	115		135		135		135		
	C_{rss}		30		50		50		50		
Switching^c											
Turn-On Time	t_{ON}	$V_{DD} = 60 \text{ V}, R_L = 150 \Omega$ $I_D \cong 0.4 \text{ A}, V_{GEN} = 10 \text{ V}$ $R_G = 25 \Omega$	5		35					ns	
	$t_{d(on)}$		3				8		8		
	t_f		2				8		8		
Turn-Off Time	t_{OFF}		26		60						
	$t_{d(off)}$		20				23		23		
	t_f		6				24		34		

Notes

- a. For DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: $PW \leq 300 \mu\text{s}$ duty cycle $\leq 2\%$.
- c. Switching time is essentially independent of operating temperature.

VNDB24

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)


TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)
